2N2218-2N2219

## HIGH-SPEED SWITCHES

## DESCRIPTION

The 2N2218, 2N2219, 2N2221 and 2N2222 are silicon planar epitaxial NPN transistors in Jedec TO-39 (for 2N2218 and 2N2219) and in Jedec TO-18 (for 2N2221 and 2N2222) metal cases. They are designed for high-speed switching applications at collector currents up to 500 mA , and feature useful current gain over a wide range of collector current, low leakage currents and low saturation voltages.

2N2218/2N2219 approved to CECC 50002100, 2N2221/2N2222 approved to CECC 50002-101 available on request.


INTERNAL SCHEMATIC DIAGRAM


## ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {CBO }}$ | Collector-base Voltage ( $\mathrm{I}_{\mathrm{E}}=0$ ) | 60 | V |
| $\mathrm{V}_{\text {CEO }}$ | Collector-emitter Voltage ( $\mathrm{I}_{\mathrm{B}}=0$ ) | 30 | V |
| $V_{\text {EBO }}$ | Emitter-base Voltage ( $\mathrm{I}_{\mathrm{C}}=0$ ) | 5 | V |
| $I_{C}$ | Collector Current | 0.8 | A |
| $P_{\text {tot }}$ | $\begin{aligned} & \text { Total Power Dissipation at } T_{\text {amb }} \leq 25^{\circ} \mathrm{C} \\ & \text { for } 2 \mathrm{~N} 2218 \text { and } 2 \mathrm{~N} 2219 \\ & \text { for } 2 \mathrm{~N} 2221 \text { and } 2 \mathrm{~N} 2222 \\ & \text { at } T_{\text {case }} \leq 25^{\circ} \mathrm{C} \\ & \text { for } 2 \mathrm{~N} 2218 \text { and } 2 \mathrm{~N} 2219 \\ & \text { for } 2 \mathrm{~N} 2221 \text { and } 2 \mathrm{~N} 2222 \end{aligned}$ | $\begin{gathered} 0.8 \\ 0.5 \\ \\ 3 \\ 1.8 \end{gathered}$ | W <br> W <br> W <br> W |
| $\mathrm{T}_{\mathrm{stg}}$ | Storage Temperature | -65 to 200 | ${ }^{\circ} \mathrm{C}$ |
| T | Junction Temperature | 175 | ${ }^{\circ} \mathrm{C}$ |

THERMAL DATA

|  |  |  | $\begin{aligned} & \text { 2N2218 } \\ & \text { 2N2219 } \end{aligned}$ | $\begin{aligned} & \text { 2N2221 } \\ & \text { 2N2222 } \end{aligned}$ |
| :---: | :---: | :---: | :---: | :---: |
| $R_{\text {th j-case }}$ $\mathrm{R}_{\text {th } \mathrm{j}-\mathrm{amb}}$ | Thermal Resistance Junction-case Thermal Resistance Junction-ambient | Max <br> Max | $\begin{gathered} 50^{\circ} \mathrm{C} / \mathrm{W} \\ 187.5^{\circ} \mathrm{C} / \mathrm{W} \end{gathered}$ | $\begin{aligned} & 83.3^{\circ} \mathrm{C} / \mathrm{W} \\ & 300^{\circ} \mathrm{C} / \mathrm{W} \end{aligned}$ |

ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| Symbol | Parameter | Test Conditions |  | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| I cbo | Collector Cutoff Current $\left(I_{E}=0\right)$ | $\begin{aligned} & \mathrm{V}_{C B}=50 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CB}}=50 \mathrm{~V} \end{aligned}$ | $T_{\mathrm{amb}}=150^{\circ} \mathrm{C}$ |  |  | $\begin{aligned} & 10 \\ & 10 \end{aligned}$ | $\begin{aligned} & \mathrm{nA} \\ & \mu \mathrm{~A} \\ & \hline \end{aligned}$ |
| $\mathrm{I}_{\text {Ebo }}$ | Emitter Cutoff Current $\left(\mathrm{I}_{\mathrm{C}}=0\right)$ | $V_{E B}=3 \mathrm{~V}$ |  |  |  | 10 | nA |
| $V_{\text {(BR) } \mathrm{CBO}}$ | Colllector-base Breakdown <br> Voltage ( $\mathrm{I}_{\mathrm{E}}=0$ ) | $\mathrm{I}_{\mathrm{C}}=10 \mu \mathrm{~A}$ |  | 60 |  |  | V |
| $\mathrm{V}_{\text {(BR)CEO }}{ }^{*}$ | Collector-emitter Breakdown Voltage ( $\mathrm{I}_{\mathrm{B}}=0$ ) | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}$ |  | 30 |  |  | V |
| $V_{\text {(BR) } \mathrm{EBO}}$ | Emittter-base Breakdown <br> Voltage ( $I_{C}=0$ ) | $\mathrm{I}_{\mathrm{E}}=10 \mu \mathrm{~A}$ |  | 5 |  |  | V |
| $V_{C E}$ (sat) ${ }^{*}$ | Collector-emitter Saturation Voltage | $\begin{aligned} & I_{C}=150 \mathrm{~mA} \\ & I_{C}=500 \mathrm{~mA} \end{aligned}$ | $\begin{aligned} & I_{B}=15 \mathrm{~mA} \\ & I_{B}=50 \mathrm{~mA} \end{aligned}$ |  |  | $\begin{aligned} & 0.4 \\ & 1.6 \\ & \hline \end{aligned}$ | $\begin{aligned} & \mathrm{v} \\ & \mathrm{v} \end{aligned}$ |
| $V_{B E}$ (sat) ${ }^{*}$ | Base-emitter Saturation Voltage | $\begin{aligned} & I_{C}=150 \mathrm{~mA} \\ & I_{C}=500 \mathrm{~mA} \end{aligned}$ | $\begin{aligned} & I_{B}=15 \mathrm{~mA} \\ & I_{B}=50 \mathrm{~mA} \end{aligned}$ |  |  | $\begin{aligned} & 1.3 \\ & 2.6 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{h}_{\text {FE }}{ }^{*}$ | DC Current Gain | $\begin{aligned} & \text { for } 2 \mathrm{~N} 2218 \\ & \mathrm{I}_{\mathrm{C}}=0.1 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=150 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=500 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=150 \mathrm{~mA} \\ & \text { for } 2 \mathrm{~N} 2219 \\ & \mathrm{I}_{\mathrm{C}}=0.1 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=150 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=500 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=150 \mathrm{~mA} \end{aligned}$ | $\begin{aligned} & \text { and } 2 \mathrm{~N} 2221 \\ & V_{C E}=10 \mathrm{~V} \\ & V_{C E}=10 \mathrm{~V} \\ & V_{C E}=10 \mathrm{~V} \\ & V_{C E}=10 \mathrm{~V} \\ & V_{C E}=10 \mathrm{~V} \\ & V_{C E}=1 \mathrm{~V} \\ & \text { and 2N2222 } \\ & V_{C E}=10 \mathrm{~V} \\ & V_{C E}=10 \mathrm{~V} \\ & V_{C E}=10 \mathrm{~V} \\ & V_{C E}=10 \mathrm{~V} \\ & V_{C E}=10 \mathrm{~V} \\ & V_{C E}=1 \mathrm{~V} \end{aligned}$ | $\begin{gathered} 20 \\ 25 \\ 35 \\ 40 \\ 20 \\ 20 \\ \\ 35 \\ 50 \\ 75 \\ 100 \\ 30 \\ 50 \end{gathered}$ |  | $120$ |  |
| $\mathrm{f}_{T}$ | Transition Frequency | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=20 \mathrm{~mA} \\ & \mathrm{f}=100 \mathrm{MHz} \end{aligned}$ | $\mathrm{V}_{\text {CE }}=20 \mathrm{~V}$ | 250 |  |  | MHz |
| $\mathrm{C}_{\text {Cbo }}$ | Collector-base Capacitance | $\begin{aligned} & \mathrm{I}_{\mathrm{E}}=0 \\ & \mathrm{f}=100 \mathrm{kHz} \end{aligned}$ | $\mathrm{V}_{\mathrm{CB}}=10 \mathrm{~V}$ |  |  | 8 | pF |
| $\mathrm{R}_{\text {e(hie) }}$ | Real Part of Input Impedance | $\begin{aligned} & I_{\mathrm{c}}=20 \mathrm{~mA} \\ & \mathrm{f}=300 \mathrm{MHz} \end{aligned}$ | $\mathrm{V}_{\text {CE }}=20 \mathrm{~V}$ |  |  | 60 | $\Omega$ |

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[^0]:    * Pulsed : pulse duration $=300 \mu$ s, duty cycle $=1 \%$.

